TRANSMITTAL LETTER (General - Patent Pending)

Docket No. 11675.76.3

			
In Re Application Of: San	ndhu, et al.		
Serial No. 09/627,649	Filing Date July 28, 2000	Examiner Not yet assigned	Group Art Unit 2811
Title: INTERLEVEL DI	ELECTRIC STRUCTURE		
Transmitted herewith is: Transmittal Letter (1 pg. Transmittal of Information Disclosure of Information Disclosure of Postcard in the above identified apprenticular in the above iden	in duplicate); on Disclosure Statement (2 pgs. Citation (2 pgs.); tatement (3 pgs.);	MMISSIONER FOR PATENTS:	CENVEL MAN CONTRACTOR OF THE PROPERTY OF THE P
 No additional fee is A check in the amo The Assistant Com as described below □ Charge the □ Credit any 	required. unt of is atta missioner is hereby authorized . A duplicate copy of this shee	to charge and credit Deposit Accou	unt No. 23-3178
Reg. No. 34,521	nature	Dated: November 2000	ment and fee is being deposited
022901		on / S Loof first class mail under 37 (ment and fee is being deposited ✓ with the U.S. Postal Service as C.F.R. 1.8 and is addressed to the for Patents Washington D.C.

· NEERADI MARKOHITEE

 $p_{t+1,\cdots}$ Signatur, 49 Person Mailing Correspondence

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Bradley K. DeSandro

Typed or Printed Name of Person Mailing Correspondence

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT Docket No. (Under 37 CFR 1.97(b) or 1.97(c)) 11675.76.3 In Re Application Of: Sandhu, et al. Serial No. Filing Date Examiner Group Art Unit July 28, 2000 09/627.649 2811 Not yet assigned Title: **DIELECTRIC STRUCTURE** INTERLEVE MOV 0 5 2000 Address to **Assistant Commissioner for Patents** Washington, D.C. 20231 37 CFR 1.97(b) The Information Disclosure Statement submitted herewith is being filed within three months of the filing 1. 🛛 of a national application; within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; or before the mailing date of a first Office Action on the merits, whichever event occurs last. 37 CFR 1.97(c) The Information Disclosure Statement submitted herewith is being filed after three months of the filing 2. of a national application, or the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; or after the mailing date of a first Office Action on the merits, whichever occurred last but before the mailing date of either: RECEIVED 1. a Final Action under 37 CFR 1.113, or 2. a Notice of Allowance under 37 CFR 1.311, whichever occurs first. Also submitted herewith is: a certification as specified in 37 CFR 1.97(e); OR the fee set forth in 37 CFR 1.17(p) for submission of an Information Disclosure Statement under 37 CFR 1.97(c).

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT Docket No. (Under 37 CFR 1.97(b) or 1.97(c)) 11675.76.3 In Re Application Of: Sandhu, et al. Serial No. Filing Date Examiner Group Art Unit 09/627,649 July 28, 2000 Not yet assigned 2811 Title: DESCECTRIC STRUCTURE INTERLEVE NOV 0 5 2000 Payment of Fee (Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p)) A check in the amount of is attached. The Assistant Commissioner is hereby authorized to charge and credit Deposit Account No. 23-3178 as described below. A duplicate copy of this sheet is enclosed. Charge the amount of Credit any overpayment. XCharge any additional fee required. Certificate of Transmission by Facsimile* Certificate of Mailing by First Class Mail certify that this document and fee is being deposited certify that this document and authorization to charge on / 2 / 52 with the U.S. Postal Service as deposit account is being facsimile transmitted to the United first class mail under 37 C.F.R. 1.8 and is addressed to the States Patent and Trademark Office (Fax. No. Assistant Commissioner for Patents, Washington, D.C.) on (Date)

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Signature

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Bradley K. DeSandro Reg. No. 34,521

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Dated: November , 2000

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Typed or Printed Name of Person Mailing Correspondence

- VOLNETRADEMARK OFFICE

PATENT APPLICATION
Docket No: 11675.76.3

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application o	f:)
	Sandhu, et al.)
Serial No.:	09/627,649) Art Unit) 2811
Filed:	July 28, 2000) 2011
For:	INTERLEVEL DIELECTRIC STRUCTURE)
Examiner:	Not yet assigned))

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97

Assistant Commissioner for Patents Washington, D.C. 20231

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Sir:

Please find, pursuant to 37 C.F.R. § 1.98(a)(1), the enclosed Form PTO-1449 which contains a list of all patents, publications, or other items that have come to the attention of one or more of the individuals designated in 37 C.F.R. § 1.56(c). While no representation is made that any of these references may be "prior art" within the meaning of that term under 35 U.S.C. §§ 102 or 103, the enclosed list of references is disclosed so as to fully comply with the duty of disclosure set forth in 37 C.F.R. § 1.56.

Moreover, while no representation is made that a specific search of office files or patent office records has been conducted or that no better art exists, the undersigned attorney

Statement of References Previously Disclosed Under 37 C.F.R. § 1.98(d)

The following listed references are not enclosed because, under 37 C.F.R. § 1.98(d), they were previously cited by or submitted to the Office in application number 08 677,514, filed on July 10, 1996, which is relied upon for an earlier filing date under 35 U.S.C. § 120.

United States Patent Documents

Patent	Issue			Sub	Filing
Number	<u>Date</u>	<u>Name</u>	<u>Class</u>	<u>Class</u>	_Date
5,445,996	8/95	Kodera et al.	438	633	
5,486,493	1/96	Jeng	438	623	
5,399,235	3/95	Mutsäers et al.	438	633	
5,420,075	5/95	Homma et al.	438	624	
5,599,740	2/97	Jang et al.	438	626	
5,677,239	10/97	Isobe	438	633	
5,795,829	8/98	Shen	438	694	
5,708,303	1/98	Jeng	257	758	

Other Documents

M.K. Jain et al., "Advanced Metalization and Interconnect systems for ULSI Applications: Homogenous and Multilayer Low-K Interlevel Dielectric Architectures for Capacitance Reduction," Conference at University of California, Berkeley, California, October 1996.

Tetsuya Homma, "Fluorinated SiO₂ Films for Interlayer Dielectrics in Quarter-Micron ULSI Multilevel Interconnections," Mat. Res. Soc. Symp. Proc., vol. 381, pp. 239-248, 1995.

J. Wary et al., "Vacuum-Deposited Parylene AF-4: A Thermally Stable, Low Dielectric Constant Polymer For Interlayer Dielectric Use," <u>DUMIC Conference</u>, pp. 207-213, February, 1996.

Dated this ____ day of October, 2000.

Respectfully submitted,

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